Improved thermoelectric performance of CuGaTe₂ with convergence of band valleys:A first-principles study

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FIG. 1: (a) The energy band of CuGaTe₂. Top of the valence band is set to zero; (b) power factors with respect to relaxation time, $\frac{S^2\sigma}{\tau}$ (unit in 10¹¹ WK⁻²m⁻¹s⁻¹).

The structure of CuGaTe₂ was optimized using the Vienna *ab initio* simulation package (VASP) based on density functional theory (DFT) with the exchange-correlation potential Perdew-Burke-Ernzerhof (PBE) with generalized-gradient approximation (GGA). The optimized lattice parameters by PBE are a = 6.103 Å, c = 12.186 Å, respectively. Then, self-consistent calculation are carried out with TB-mBJ exchange-correlation potential as implemented in the WIEN2k package and transport properties are calculated. Fig. S1(a) displayed the energy band gap is 0.75 eV. The power factors with respect to relaxation time at 800 and 950 K are shown in Fig. S1(b). We find n-type CuGaTe₂ also displaying better thermoelectric properties than the p-type CuGaTe₂ with the direct gap electronic structure because the M and Gamma points near CBM can also be regarded as nearly converged.

FIGURE CAPTIONS

Fig. S1. (a) The energy band of CuGaTe₂. Top of the valence band is set to zero; (b) power factors with respect to relaxation time, $\frac{S^2\sigma}{\tau}$ (unit in 10¹¹WK⁻²m⁻¹s⁻¹).